

# RBE012N10R1SZPW

REXFET-1 N-Channel Power MOSFET

100 V - 350 A - 1.2 m $\Omega$  - TOLT

#### **Description**

The RBE012N10R1SZPW N-channel power MOSFET features REXFET-1 split-gate technology and is offered in a TOLT package. The TOLT package features top-side cooling for ultra-compact and optimal thermal performance. Renesas' REXFET-1 split gate technology is suitable for applications requiring low RDS(on) and switching capability for high-power and high-frequency applications.

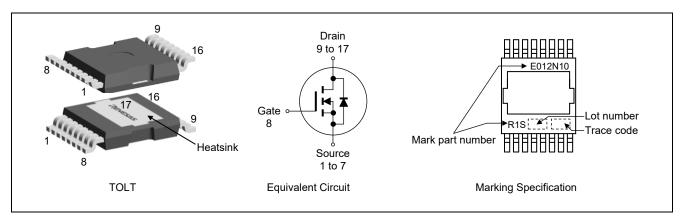
#### **Features**

- Standard level gate drive voltage: V<sub>GS(th)</sub> = 2.0 to 4.0 V
- Super low on-state resistance:  $R_{DS(on)} = 1.2 \text{ m}\Omega$  Max.
- Low input capacitance
- Low thermal resistance
- 100% Avalanche tested
- Pb-free lead plating: RoHS compliant
- MSL1 classified according to IPC/JEDEC J-STD-020

#### **Application**

Motor Control, Energy Infrastructure, Industrial Automation, DC-DC Power Conversion, Power Tools, Robotics

#### **Outline**



#### **Absolute Maximum Ratings**

(Tj = 25 °C unless otherwise notice.)

Item	Symbol	Ratings	Unit
Drain to Source Voltage	V <sub>DSS</sub>	100	V
Gate to Source Voltage	V <sub>GSS</sub>	±20	V
Drain Current (DC)	ID(DC) Tc=25°C Note 2,6	±350	A
	ID(DC) Tc=100°C <sup>Note 2,6</sup>	±325	A
Drain Current (pulse)	I <sub>D(pulse)</sub> Note 1,3,6	±1400	A
Power Dissipation	P <sub>D</sub> Note 1,6	535	W
Operating Junction Temperature	Tj	-55 to 175	°C
Storage Temperature	T <sub>stg</sub>	-55 to 175	°C
Single Avalanche Current	IAS Note 4	79	A
Single Avalanche Energy	Eas Note 4	624	mJ

# **Thermal Resistance**

Item	Symbol	Max.	Unit
Junction to Case Thermal Resistance	Rth(j-c) Note 6	0.28	°C/W
Junction to Ambient Thermal Resistance	Rth(j-a) Note 5,6	40	°C/W

# **Electrical Characteristics**

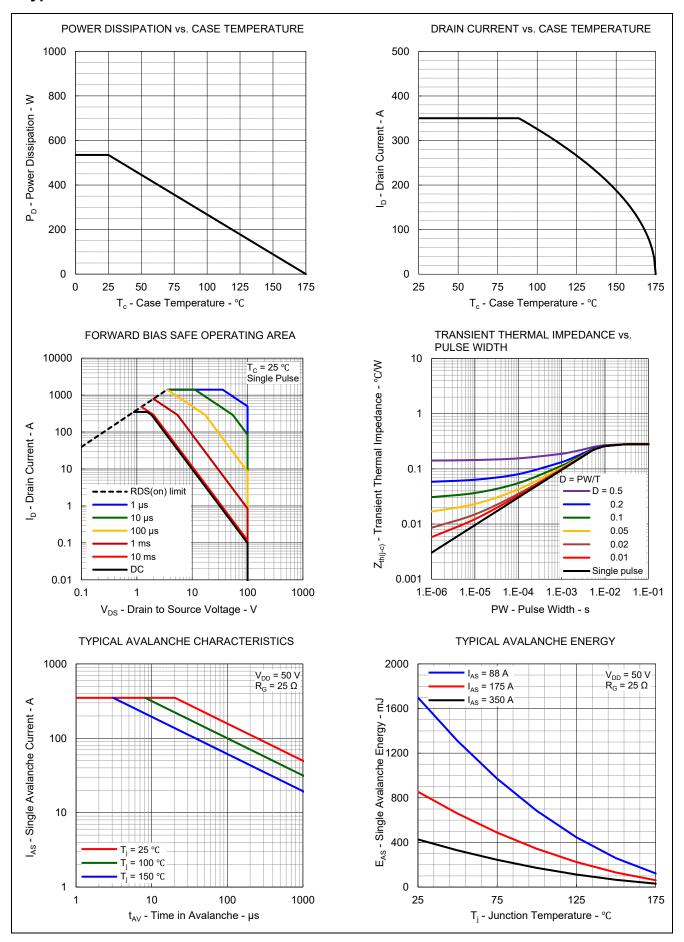
 $(T_j = 25 \, ^{\circ}C \text{ unless otherwise notice.})$ 

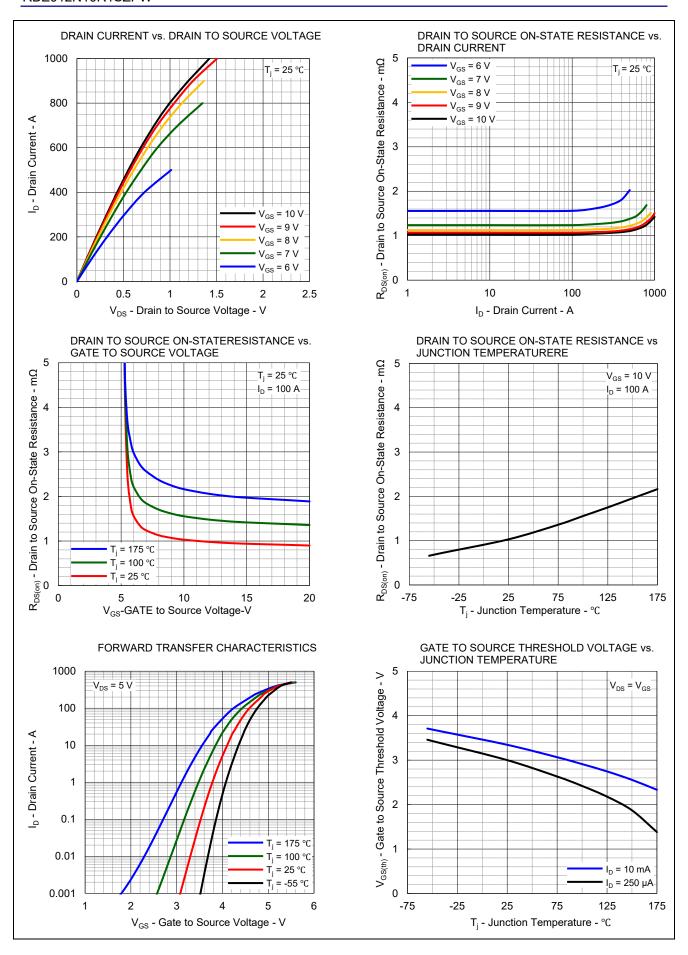
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	10	μA	V <sub>DS</sub> = 100 V, V <sub>GS</sub> = 0 V
Gate Leakage Current	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$
Gate to Source Threshold Voltage	$V_{GS(th)}$	2.0	_	4.0	V	$V_{DS} = V_{GS}, I_{D} = 250 \ \mu A$
Drain to Source On-state Resistance	R <sub>DS(on)</sub>	_	1.03	1.2	mΩ	V <sub>G</sub> S = 10 V, I <sub>D</sub> = 100 A
Input Capacitance	C <sub>iss</sub>	_	17000	_	pF	V <sub>DS</sub> = 50 V
Output Capacitance	C <sub>oss</sub>	_	4000	_	pF	V <sub>GS</sub> = 0 V
Reverse Transfer Capacitance	C <sub>rss</sub>	_	110	_	pF	f = 100 kHz
Gate resistance	R <sub>g</sub>	_	1.8	_	Ω	_
Turn-on Delay Time	t <sub>d(on)</sub>	_	100	_	ns	V <sub>DD</sub> = 50 V
Rise Time	t <sub>r</sub>	_	70	_	ns	I <sub>D</sub> = 100 A
Turn-off Delay Time	$t_{d(off)}$	_	210	_	ns	V <sub>GS</sub> = 10 V
Fall Time	t <sub>f</sub>	_	75	_	ns	$R_G = 5 \Omega$
Total Gate Charge	Q <sub>g</sub>	_	230	_	nC	V <sub>DD</sub> = 50 V
Gate to Source Charge	$Q_{gs}$	_	90	_	nC	V <sub>GS</sub> = 10 V
Gate to Drain Charge	$Q_{gd}$	_	41	_	nC	I <sub>D</sub> = 100 A
Gate plateau voltage	V <sub>plateau</sub>	_	5.3	_	V	
Output Charge	Q <sub>oss</sub>	_	360	_	nC	V <sub>DD</sub> = 50 V, V <sub>GS</sub> = 0 V
Body Diode Forward Voltage	V <sub>F(S-D)</sub>	_	0.83	1.5	V	I <sub>F</sub> = 100 A, V <sub>GS</sub> = 0 V
Reverse Recovery Time	t <sub>rr</sub>	_	120	_	ns	I <sub>F</sub> = 100 A, V <sub>GS</sub> = 0 V
Reverse Recovery Charge	Q <sub>rr</sub>	_	400	_	nC	di/dt = 100 A/μs

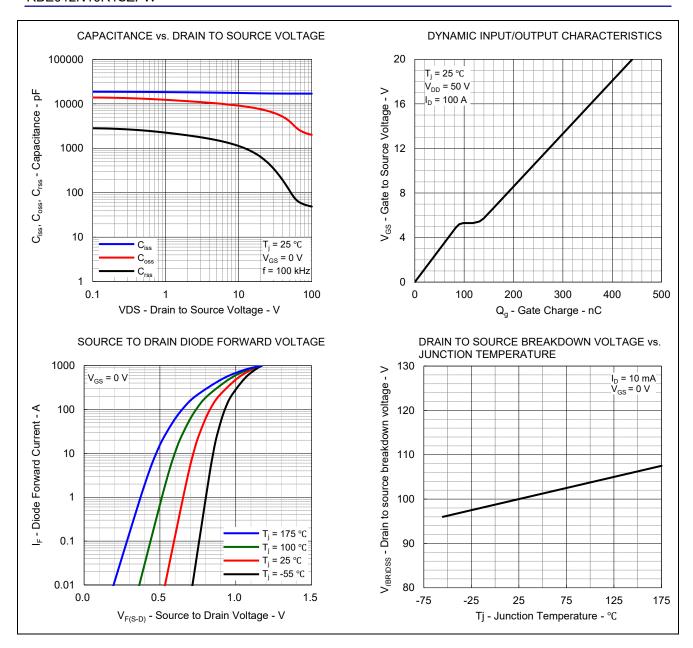
Note 1.  $T_c$  = 25 °C

- 2. Value is limited by overall system design including PCB.
- 3. PW  $\leq$  100  $\mu$ s
- 4. L = 100  $\mu$ H, V<sub>DD</sub> = 50 V, R<sub>G</sub> = 25  $\Omega$
- 5. Device on 40 mm x 40 mm x 1.5 mm epoxy PCB FR4. (2 oz Cu pad.)
- 6. Defined by design. Not subject to production test.

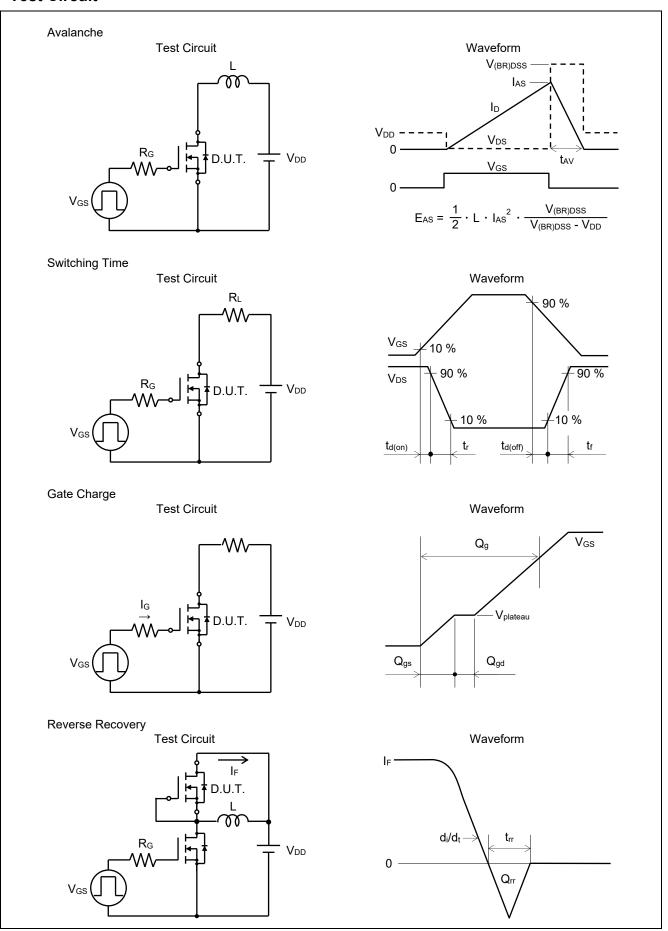
### **Typical Characteristics**



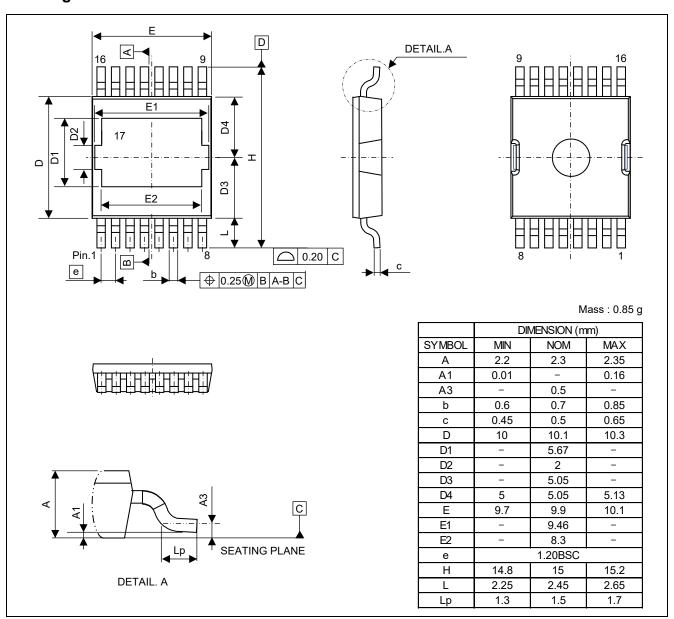




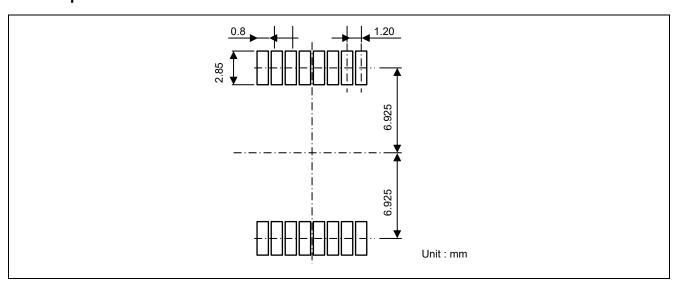
# **Test Circuit**



# **Package Dimensions**



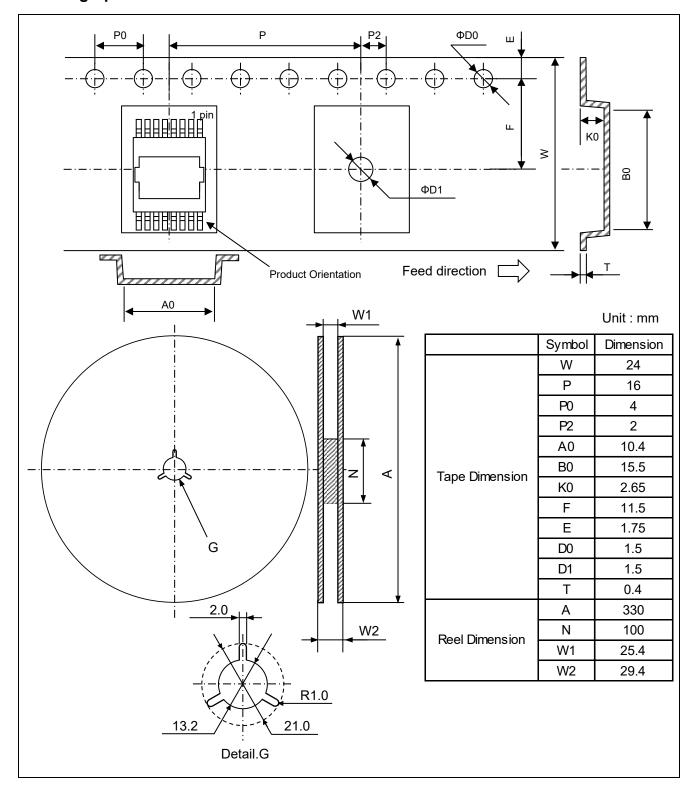
# **Mount pad**



# **Ordering Information**

Part No.	Packing	Quantity
RBE012N10R1SZPW#KB0	Taping	1300pcs/reel

# **Packing Specification**



Remark: Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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